

Features

1. Current transfer ratio
(CTR:MIN.50% at IF=5mA Vce=5V)
2. High isolation voltage between input and output
(Viso:5000Vrms).
3. Compact dual-in-line package.
4. Available package : DIP/ SMD/ H. (For Package Dimension please refer to page 83)

Applications

1. Registers, copiers, automatic vending machines.
2. System appliances, measuring instruments.
3. Computer terminals, programmable controllers.
4. Communications, telephone, etc.
5. Electric home appliances, such as oil fan heaters, Microwave oven, Washer, Refrigerator, Air conditioner, etc.
6. Medical instruments, physical and chemical equipment.
7. Signal transmission between circuits of different potentials and impedances.
8. Facsimile equipment, Audio, Video.
9. Switching power supply, Laser beam printer.

Absolute Maximum Ratings

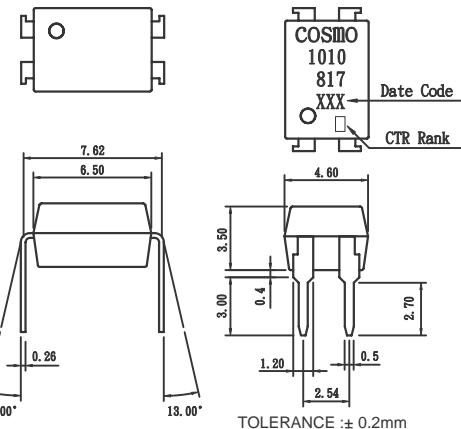
Parameter		Symbol	Rating	Unit
Input	Forward current	IF	50	mA
	Peak forward current	IFM	1	A
	Reverse voltage	VR	6	V
	Power dissipation	PD	70	mW
Output	Collector-emitter voltage	VCEO	60	V
	Emitter-collector voltage	VECO	6	V
	Collector current	Ic	50	mA
	Collector power dissipation	Pc	150	mW
Total power dissipation		Ptot	200	mW
Isolation voltage 1 minute		Viso	5000	Vrms
Operating temperature		Topr	-30 to +100	°C
Storage temperature		Tstg	-55 to +125	°C
Soldering temperature 10 second		Tsol	260	°C

Electro-optical Characteristics

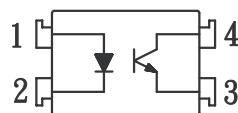
(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	VF	IF=20mA	—	1.2	1.4	V
	Peak forward voltage	VFM	IFM=0.5A	—	—	3.0	V
	Reverse current	IR	VR =4V	—	—	10	uA
	Terminal capacitance	Ct	V=0, f=1kHz	—	30	—	pF
Output	Collector dark current	ICEO	VCE =20V	—	—	0.1	uA
Transfer characteristics	Current transfer ratio	CTR	IF=5mA, VCE =5V	50	—	600	%
	Collector-emitter saturation voltage	VCE(sat)	IF=20mA, Ic=1mA	—	0.1	0.2	V
	Isolation resistance	Riso	DC500V	5X10 ¹⁰	10 ¹¹	—	ohm
	Floating capacitance	Cf	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	fc	VCC=5V, Ic=2mA, RL=100ohm	—	80	—	kHz
	Response time(Rise)	tr	VCE=2V, Ic=2mA, RL=100ohm	—	4	18	us
	Response time(Fall)	tf		—	3	18	us

Outside Dimension : Unit (mm)



Schematic : Top View



1. Anode
2. Cathode
3. Emitter
4. Collector

Searchdatasheet.com

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	VF	IF=20mA	—	1.2	1.4	V
	Peak forward voltage	VFM	IFM=0.5A	—	—	3.0	V
	Reverse current	IR	VR =4V	—	—	10	uA
	Terminal capacitance	Ct	V=0, f=1kHz	—	30	—	pF
Output	Collector dark current	ICEO	VCE =20V	—	—	0.1	uA
Transfer characteristics	Current transfer ratio	CTR	IF=5mA, VCE =5V	50	—	600	%
	Collector-emitter saturation voltage	VCE(sat)	IF=20mA, Ic=1mA	—	0.1	0.2	V
	Isolation resistance	Riso	DC500V	5X10 ¹⁰	10 ¹¹	—	ohm
	Floating capacitance	Cf	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	fc	VCC=5V, Ic=2mA, RL=100ohm	—	80	—	kHz
	Response time(Rise)	tr	VCE=2V, Ic=2mA, RL=100ohm	—	4	18	us
	Response time(Fall)	tf		—	3	18	us

Classification table of current transfer ratio is shown below.

Model NO.	CTR (%)
A	80 TO 160
B	130 TO 260
C	200 TO 400
D	300 TO 600
E	50 TO 600

Fig.1 Current Transfer Ratio vs. Forward Current

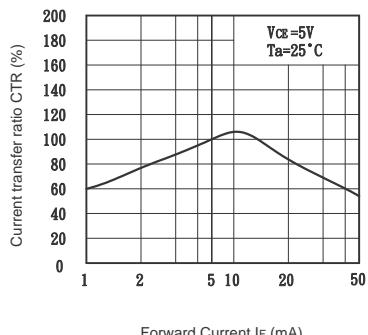


Fig.2 Collector Power Dissipation vs. Ambient Temperature

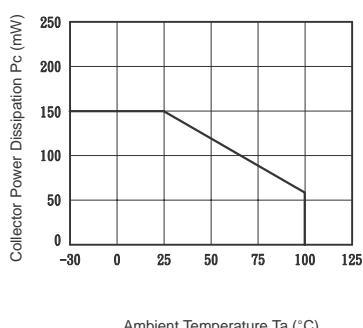


Fig.3 Collector Dark Current vs. Ambient Temperature

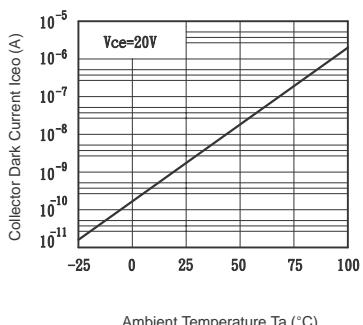


Fig.4 Forward Current vs. Ambient Temperature

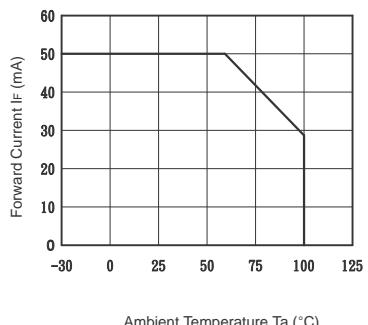


Fig.5 Forward Current vs. Forward Voltage

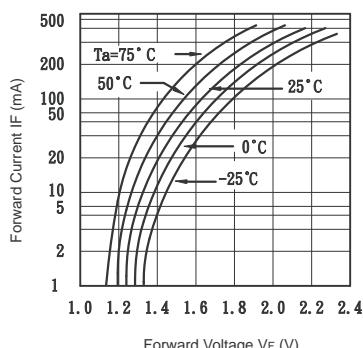


Fig.6 Collector Current vs. Collector-emitter Voltage

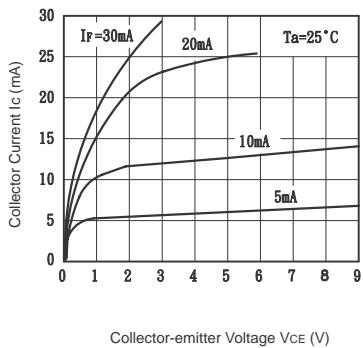


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

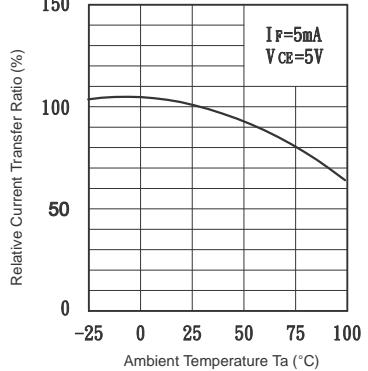


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

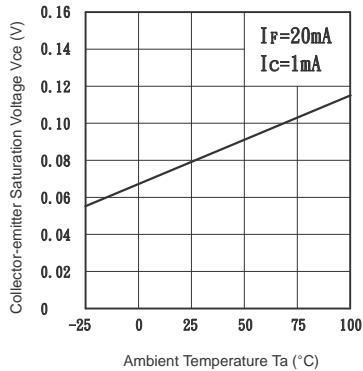


Fig.9 Collector-emitter Saturation Voltage vs. Forward Current

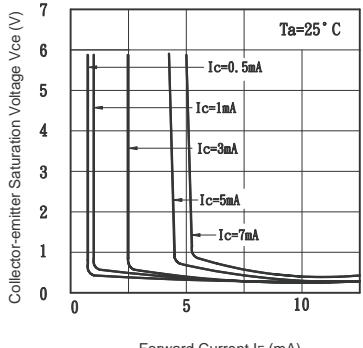


Fig.10 Response Time vs. Load Resistance

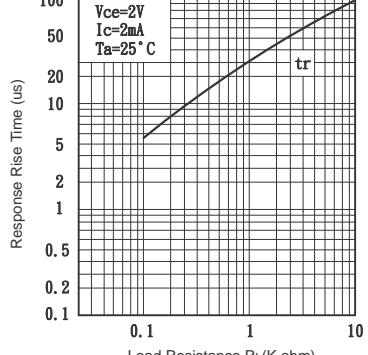


Fig.11 Response Time vs. Load Resistance

